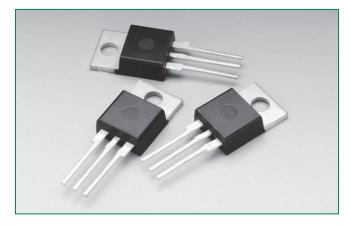


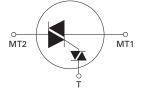
## Q6012LTH1LED Series



Agency App	roval
Agency	Agency File Number
<i>.</i> <b>Я</b>	L Package : E71639

Main Features				
Symbol	Value	Unit		
I <sub>T(RMS)</sub>	12	А		
V <sub>DRM</sub> /V <sub>RRM</sub>	600	V		
DIAC V <sub>RO</sub>	33 to 43	V		

## **Schematic Symbol**



## Description

The Quadrac is an internally triggered Triac designed for AC switching and phase control applications. It is a Triac and DIAC in a single package, which saves user expense by eliminating the need for separate Triac and DIAC components.

Q6012LTH1LED series is designed to meet low load current characteristics typical in LED lighting applications.

By keeping holding current at 8mA maximum, this Quadrac series is characterized and specified to perform best with LED loads. The Q6012LTH1LED series is best suited for LED dimming controls to obtain the lowest levels of light output with a minimum probability of flickering.

O6012LTH1LED series is offered in the industry standard TO-220AB package with an isolated mounting tab that makes it best suited for adding an external heat sink.

## Features

- As low as 8mA max holding current
- UL recognized TO-220AB package
- 110°C rated junction temperature
- di/dt performance of 70A/µs
- QUADRAC version includes intergrated DIAC

## Benefits

- Provides full control of light out put at the extreme low end of load conditions.
- 2500V <sub>AC</sub> min isolation between mounting tab and active terminals
- Improves margin of safe operation with less heat sinking required
- Enable survivability of typically LED load operating characteristics
- Simplicity of circuit design & layout

## Applications

Excellent for AC switching and phase control applications such as lighting and motor speed controls. Typical applications are AC solid-state switches, light dimmers with LED loads, small low current motor in power tools, and low current motors in home/brown goods appliances.

Internally constructed isolated package is offered for ease of heat sinking with highest isolation voltage.



## **Absolute Maximum Ratings**

Symbol	Param	Value	Unit	
I <sub>T(RMS)</sub>	RMS forward current	Tc = 90°C	12	A
I <sub>TSM</sub> Peak non-repetitive surge current	Posk pop ropotitivo surgo surront	single half cycle; f = 50Hz; T <sub>J</sub> (initial) = 25°C	110	A
	Peak non-repetitive surge current	single half cycle; f = 60Hz; T <sub>J</sub> (initial) = 25°C	120	A
l <sup>2</sup> t	l <sup>2</sup> t value for fusing	t <sub>p</sub> = 8.3ms	60	A <sup>2</sup> s
di/dt	Critical rate-of-rise of on-state current	f = 60Hz; T <sub>J</sub> =110°C	70	A/µs
I <sub>GM</sub>	Peak gate current	1.5	A	
T <sub>stg</sub>	Storage temperature range		-40 to 150	°C
T	Operating junction temperature range		-40 to 110	°C

## Electrical Characteristics (T<sub>J</sub> = 25°C, unless otherwise specified) – Alternistor Quadrac

Symbol	Test Conditions		Value	Unit
I <sub>H</sub>	I <sub>τ</sub> = 20mA (initial)	MAX.	8	mA
dv/dt	$V_{\rm D} = V_{\rm DRM}$ ; gate open; T <sub>J</sub> =110°C	MIN.	45	V/µs
dv/dt(c)	$di/dt(c) = 0.54 \times I_{T(rms)} / ms; T_{J} = 110^{\circ}C$	MIN.	2	V/µs
t <sub>gt</sub>	(note 1)	TYP.	3	μs

(1) Reference test circuit in figure 7 and waveform in figure 8;  $C_{T} = 0.1 \mu F$  with 0.1  $\mu$ s rise time.

## Trigger DIAC Specifications

Symbol	Test Conditions		Value	Unit
ΔV <sub>bo</sub>	Breakover Voltage Symmetry	MAX.	3	V
			33	
V <sub>BO</sub> Br	Breakover Voltage, forward and reverse	MAX.	43	V
[ΔV±]	Dynamic Breakback Voltage, forward and reverse (note 1)	MIN.	5	V
во	Peak Breakover Current	MAX.	25	uA
С <sub>т</sub>	Trigger Firing Capacitance	MAX.	0.1	μF

(1) Reference test circuit in figure 7 and waveform in figure 8.

## **Static Characteristics**

Symbol	Test Conditions			Value	Unit
V <sub>TM</sub>	$I_{T} = 1.41 \times I_{T(rms)} A; t_{p} = 380 \mu s$		MAX.	1.6	V
		$T_{J} = 25^{\circ}C$	N 4 A X 4	10	
I <sub>DRM</sub> /I <sub>RRM</sub>	V <sub>drm</sub> / V <sub>rrm</sub>	T <sub>J</sub> = 110°C	MAX.	1000	μΑ

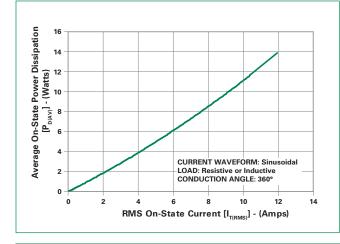
Thermal Resistances					
Symbol	Parameter	Value	Unit		
R <sub>θ(J-C)</sub>	Junction to case (AC)	2.3	°C/W		
R <sub>θ(J-A)</sub>	Junction to ambient	50	°C/W		

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Figure 1: Normalized DC Holding Current vs. Junction Temperature

# Figure 3: Power Dissipation vs. RMS On-State Current (Typical)



## Figure 5: Surge Peak On-State Current vs. Number of Cycles

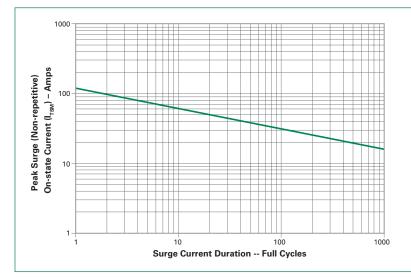
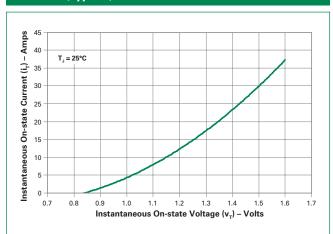
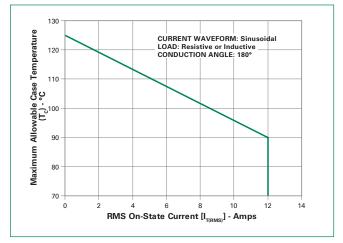


Figure 2: On-State Current vs. On-State Voltage (Typical)



# Figure 4: Maximum Allowable Case Temperature vs. RMS On-State Current



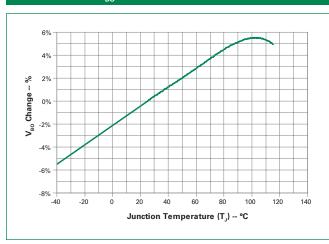
#### Notes:

- 1. Gate control may be lost during and immediately following surge current interval.
- 2. Overload may not be repeated until junction temperature has returned to steady-state rated value.

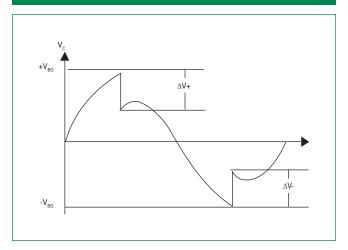
Supply Frequency: 60Hz Sinusoidal Load: Resistive RMS On-State Current: [I<sub>TRMS]</sub>]: Maximum Rated Value at Specific Case Temperature



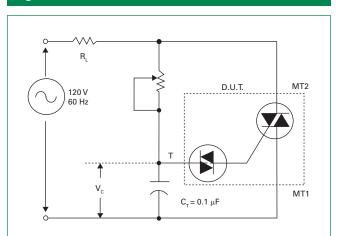
## Figure 6: DIAC V<sub>BO</sub> Change vs. Junction Temperature



## Figure 8: Test Circuit Waveform



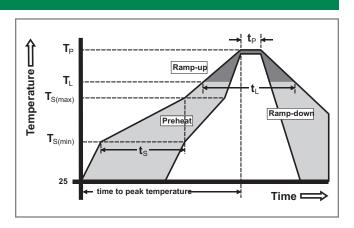
## Figure 7: Test Circuit





## **Soldering Parameters**

Reflow Condition		Pb – Free assembly	
	-Temperature Min (T <sub>s(min)</sub> )	150°C	
Pre Heat	-Temperature Max (T <sub>s(max)</sub> )	200°C	
	-Time (min to max) (t <sub>s</sub> )	60 – 180 secs	
Average ramp up rate (LiquidusTemp) (T <sub>L</sub> ) to peak		5°C/second max	
T <sub>S(max)</sub> to T <sub>L</sub> - Ramp-up Rate		5°C/second max	
Reflow	-Temperature (T <sub>L</sub> ) (Liquidus)	217°C	
Rellow	-Temperature (t <sub>L</sub> )	60 – 150 seconds	
PeakTemp	erature (T <sub>P</sub> )	260°C +0/-5	
Time within 5°C of actual peak Temperature (t <sub>p</sub> )		20 – 40 seconds	
Ramp-down Rate		5°C/second max	
Time 25°C to peak Temperature (T <sub>P</sub> )		8 minutes Max.	
Do not exceed		280°C	



Physical Specifications		
Terminal Finish	1005 Matte Tin-plated	
Body Material	UL Recognized epoxy meeting flammability classification 94v-0	
Lead Material	Copper Alloy	

### **Design Considerations**

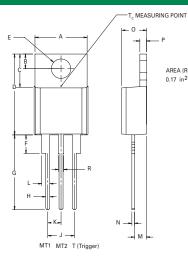
Careful selection of the correct device for the application's operating parameters and environment will go a long way toward extending the operating life of the Thyristor. Good design practice should limit the maximum continuous current through the main terminals to 75% of the device rating. Other ways to ensure long life for a power discrete semiconductor are proper heat sinking and selection of voltage ratings for worst case conditions. Overheating, overvoltage (including dv/dt), and surge currents are the main killers of semiconductors. Correct mounting, soldering, and forming of the leads also help protect against component damage.

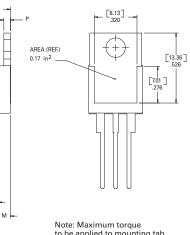
## **Environmental Specifications**

Test	Specifications and Conditions
High Temperature Voltage Blocking	MIL-STD-750: Method 1040, Condition A Rated V <sub>DRM</sub> (VAC-peak), 110°C, 1008 hours
Temperature Cycling	MIL-STD-750: Method 1051 -40°C to 150°C, 15-minute dwell, 100 cycles
Biased Temperature & Humidity	EIA/JEDEC: JESD22-A101 320VDC, 85°C, 85%RH, 1008 hours
High Temp Storage	MIL-STD-750: Method 1031 150°C, 1008 hours
Low-Temp Storage	-40°C, 1008 hours
Thermal Shock	MIL-STD-750: Method 1056 0°C to 100°C, 5-minute dwell, 10-second transfer, 10 cycles
Autoclave (Pressure Cooker Test)	EIA/JEDEC: JESD22-A102 121°C, 100%RH, 2atm, 168 hours
Resistance to Solder Heat	MIL-STD-750: Method 2031 260°C, 10 seconds
Solderability	ANSI/J-STD-002, Category 3, Test A
Lead Bend	MIL-STD-750: Method 2036, Condition E



## Dimensions - TO-220AB (L-Package) - Isolated Mounting Tab





Note: Maximum torque to be applied to mounting tab is 8 in-Ibs. (0.904 Nm).

Dimension	Incl	hes	Millimeters	
Dimension	Min	Max	Min	Max
А	0.380	0.420	9.65	10.67
В	0.105	0.115	2.67	2.92
С	0.230	0.250	5.84	6.35
D	0.590	0.620	14.99	15.75
E	0.142	0.147	3.61	3.73
F	0.110	0.130	2.79	3.30
G	0.540	0.575	13.72	14.61
Н	0.025	0.035	0.64	0.89
J	0.195	0.205	4.95	5.21
K	0.095	0.105	2.41	2.67
L	0.060	0.075	1.52	1.91
М	0.085	0.095	2.16	2.41
Ν	0.018	0.024	0.46	0.61
0	0.178	0.188	4.52	4.78
Р	0.045	0.060	1.14	1.52
R	0.038	0.048	0.97	1.22

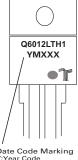
#### **Product Selector** Part Number Type Package Q6012LTH1LED Alternistor Quadrac TO-220L

Packing Options				
Part Number	Marking	Weight	Packing Mode	Base Quantity
Q6012LTH1LED	Q6012LTH1	2.2 g	Bulk	500
Q6012LTH1LEDTP	Q6012LTH1	2.2 g	Tube	500 (50 per tube)

### Part Numbering System <u>O 60 12 L T H1 LED</u> LED LIGHTING APPLICATION DEVICE TYPE Q: Quadrac TRIAC TYPE VOLTAGE RATING H1: Low Holding Current 60: 600V Alternistor Quadrac CURRENT RATING Trigger T: Internal Diac (33V – 43V) PACKAGE TYPE L: TO-220 (Isolated)

## Part Marking System

### TO-220 AB - (L Package)



Date Code Marking Y:Year Code M: Month Code XXX: Lot Trace Code